

N-channel 100 V, 1.9 mΩ typ., 180 A, STripFET™ F7 Power MOSFETs in H²PAK-2 and H²PAK-6 packages

Datasheet - production data

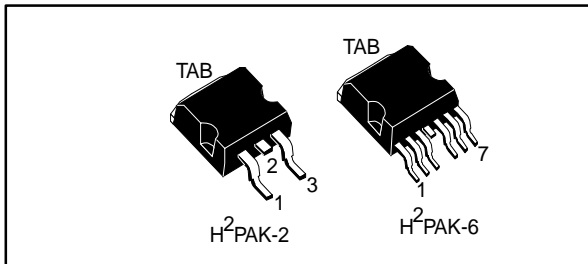
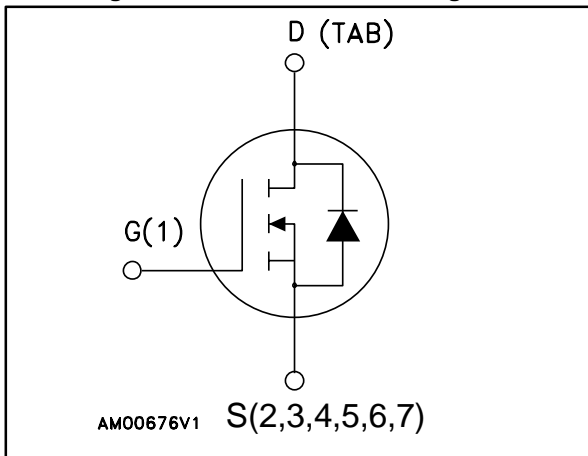


Figure 1: Internal schematic diagram



Features

Order code	V _{DS}	R _{DS(on)} max.	I _D
STH310N10F7-2	100 V	2.3 mΩ	180 A
STH310N10F7-6			

- Among the lowest R_{DS(on)} on the market
- Excellent figure of merit (FoM)
- Low C_{rss}/C_{iss} ratio for EMI immunity
- High avalanche ruggedness

Applications

- Switching applications

Description

These N-channel Power MOSFETs utilize STripFET™ F7 technology with an enhanced trench gate structure that results in very low on-resistance, while also reducing internal capacitance and gate charge for faster and more efficient switching.

Table 1: Device summary

Order code	Marking	Package	Packing
STH310N10F7-2	310N10F7	H ² PAK-2	Tape and reel
STH310N10F7-6		H ² PAK-6	

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1 Electrical ratings

Table 2: Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{DS}	Drain-source voltage	100	V
V _{GS}	Gate-source voltage	± 20	V
I _D ⁽¹⁾	Drain current (continuous) at T _C = 25 °C	180	A
	Drain current (continuous) at T _C = 100 °C	180	A
I _D ⁽²⁾	Drain current (pulsed)	720	A
P _{TOT}	Total dissipation at T _C = 25 °C	315	W
E _{AS} ⁽³⁾	Single pulse avalanche energy (T _J = 25 °C L = 0.55 mH, I _{AS} = 65 A)	1	J
T _J	Operating junction temperature	-55 to 175	°C
T _{stg}	Storage temperature		°C

Notes:

- (1)Current limited by package
- (2)Pulse width limited by safe operating area
- (3)Starting T_J = 25 °C, I_D = 60 A, V_{DD} = 50 V

Table 3: Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction-case	0.48	°C/W
R _{thj-pcb} ⁽¹⁾	Thermal resistance junction-pcb	35	°C/W

Notes:

- (1)When mounted on FR-4 board of 1 inch², 2 oz Cu

2 Electrical characteristics

(T_{CASE} = 25 °C unless otherwise specified)

Table 4: On/off-state

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V _{(BR)DSS}	Drain-source breakdown voltage (V _{GS} = 0)	I _D = 250 μA	100			V
I _{DSS}	Zero gate voltage drain current (V _{GS} = 0)	V _{DS} = 100 V			1	μA
		V _{DS} = 100 V; T _C = 125 °C			100	μA
I _{GSS}	Gate body leakage current (V _{DS} = 0)	V _{GS} = 20 V			100	nA
V _{GS(th)}	Gate threshold voltage	V _{DS} = V _{GS} , I _D = 250 μA	2.5	3.5	4.5	V
R _{DS(on)}	Static drain-source on-resistance	V _{GS} = 10 V, I _D = 60 A		1.9	2.3	mΩ

Table 5: Dynamic

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit	
C _{iss}	Input capacitance	V _{DS} = 25 V, f = 1 MHz, V _{GS} = 0	-	12800	-	pF	
C _{oss}	Output capacitance			3500		pF	
C _{rss}	Reverse transfer capacitance			170		pF	
Q _g	Total gate charge			V _{DD} = 50 V, I _D = 180 A		180	nC
Q _{gs}	Gate-source charge			V _{GS} = 10 V		78	nC
Q _{gd}	Gate-drain charge			See Figure 14: "Gate charge test circuit"		34	nC

Table 6: Switching times

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
t _{d(on)}	Turn-on delay time	V _{DD} = 50 V, I _D = 90 A, R _G = 4.7 Ω, V _{GS} = 10 V See Figure 13: "Switching times test circuit for resistive load"	-	62	-	ns
t _r	Rise time			108		ns
t _{d(off)}	Turn-off delay time			148		ns
t _f	Fall time			40		ns

Table 7: Source-drain diode

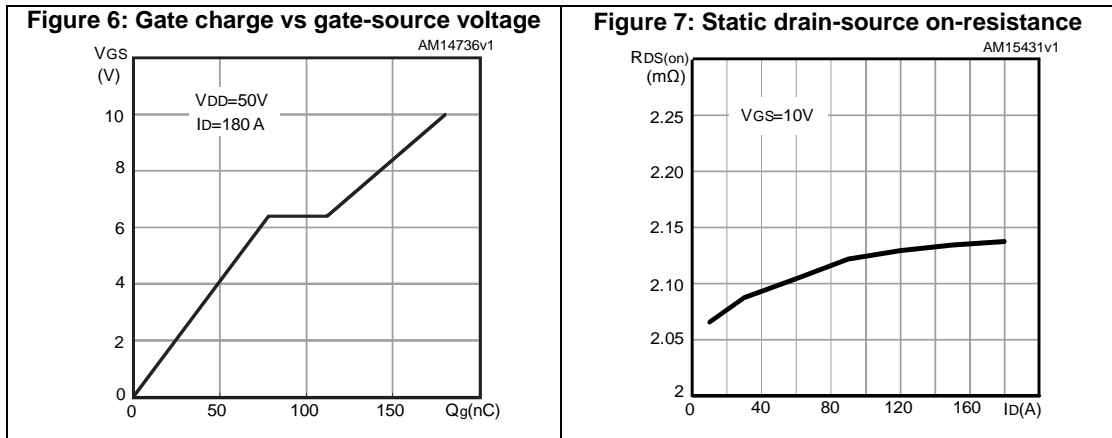
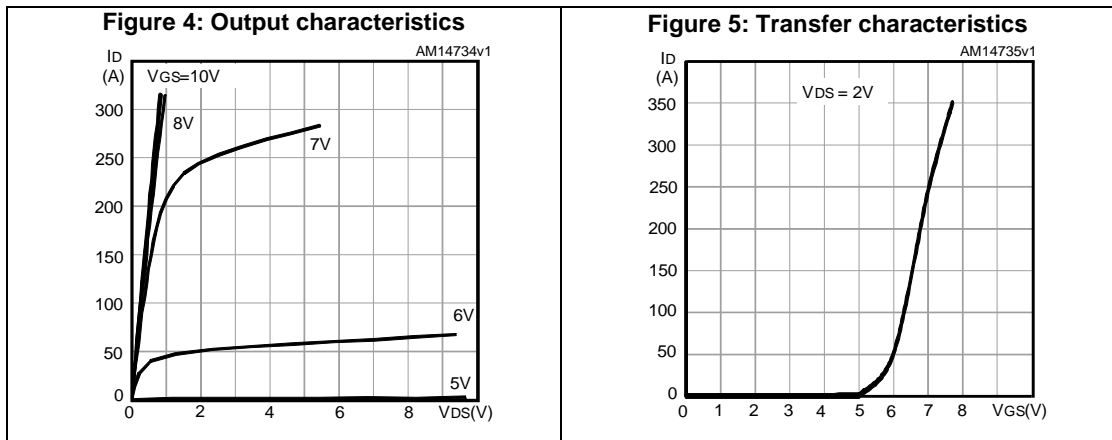
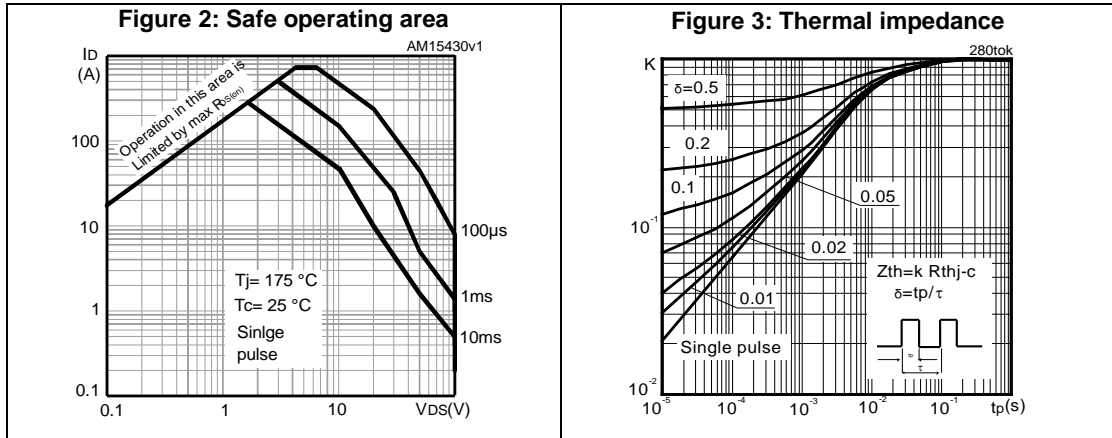
Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit		
I_{SD}	Source-drain current		-		180	A		
$I_{SDM}^{(1)}$	Source-drain current (pulsed)				720	A		
$V_{SD}^{(2)}$	Forward on voltage	$I_{SD} = 60 \text{ A}, V_{GS} = 0$				1.5	V	
t_{rr}	Reverse recovery time	$I_{SD} = 180 \text{ A},$ $di/dt = 100 \text{ A}/\mu\text{s},$ $V_{DD} = 80 \text{ V}, T_j = 150 \text{ }^\circ\text{C}$			85		ns	
Q_{rr}	Reverse recovery charge					200		nC
I_{RRM}	Reverse recovery current					4.7		A

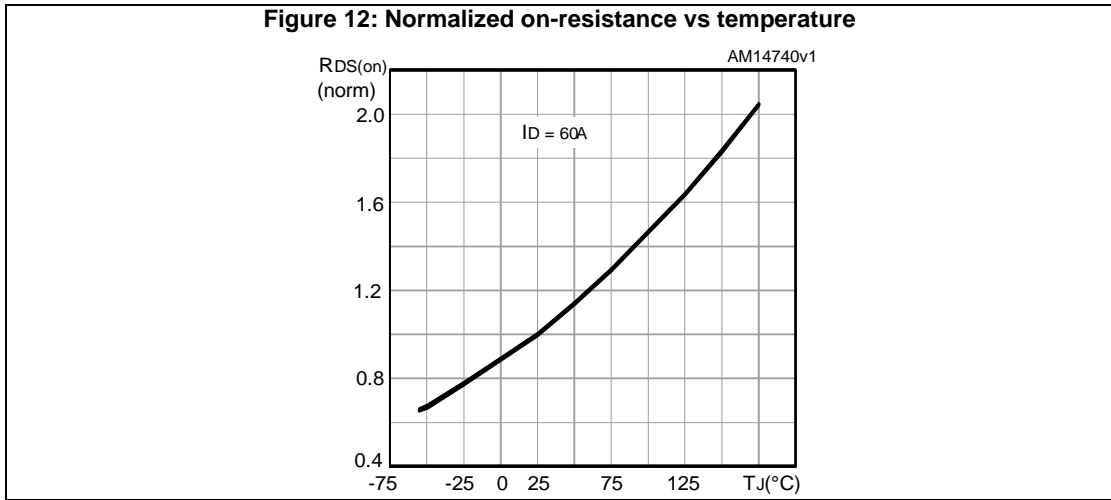
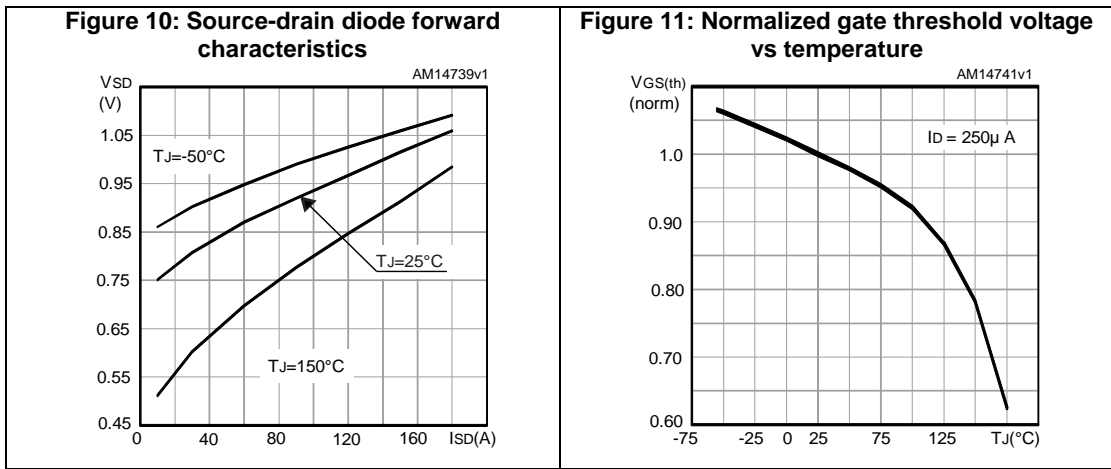
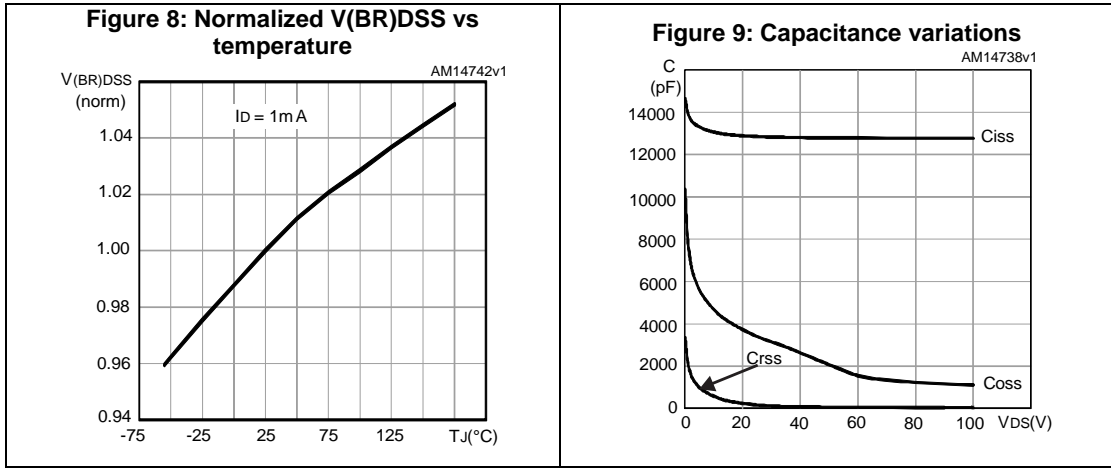
Notes:

(1)Pulse width limited by safe operating area

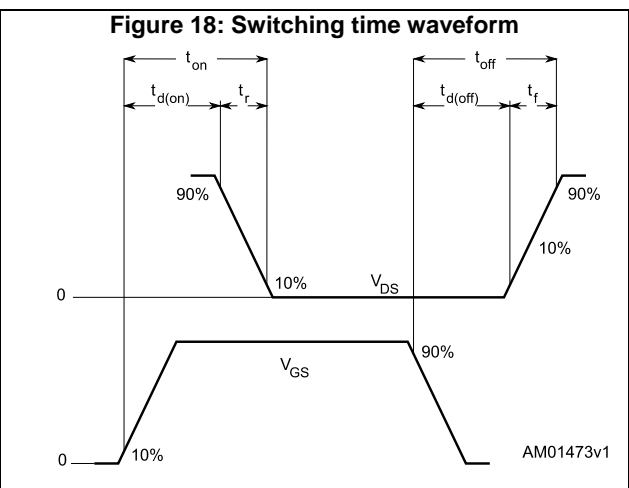
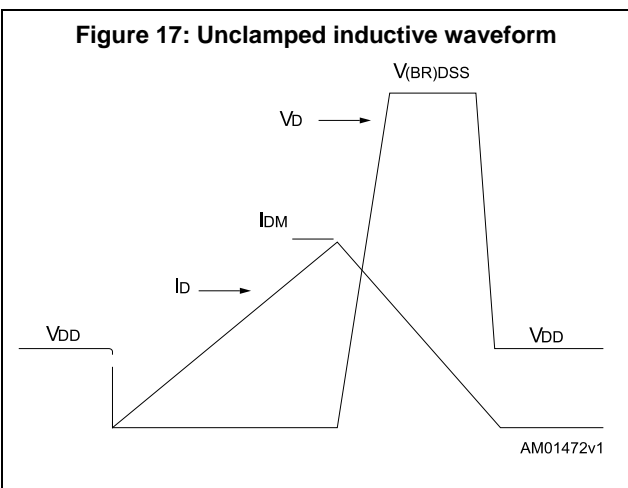
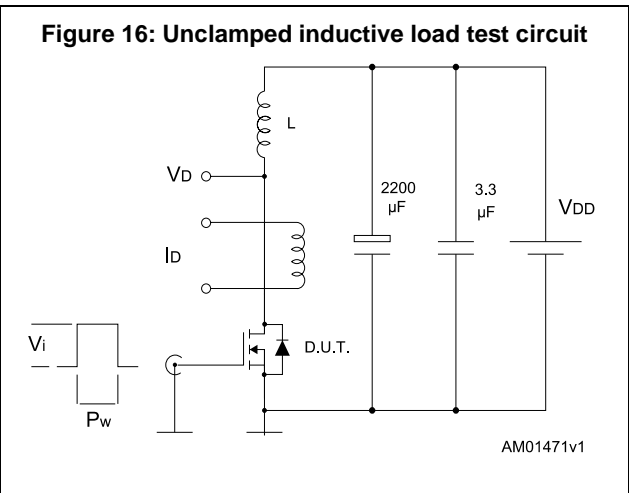
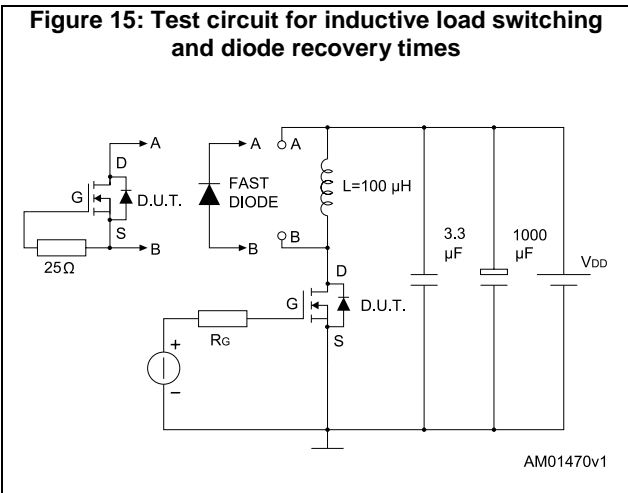
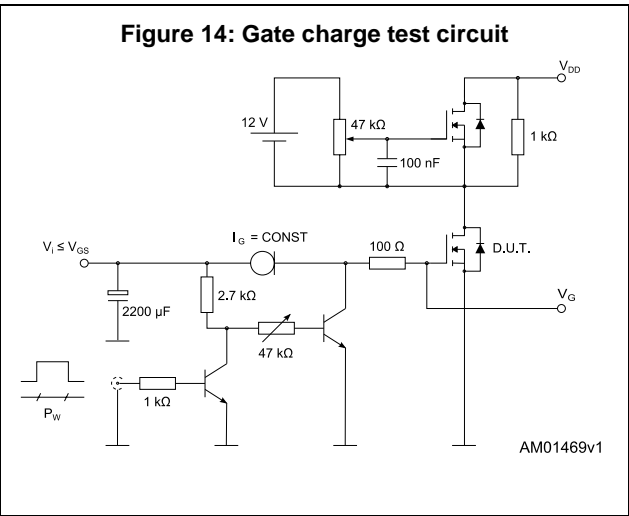
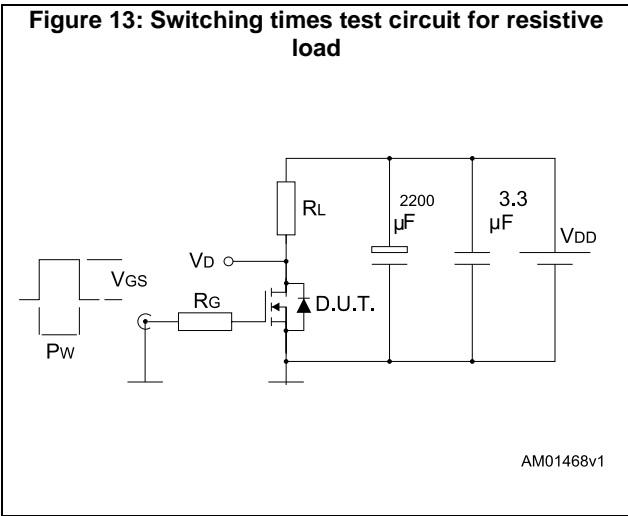
(2)Pulsed: pulse duration = 300 μs , duty cycle 1.5%

2.1 Electrical characteristics (curves)





3 Test circuits



4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

4.1 H2PAK-2 package information

Figure 19: H²PAK-2 package outline

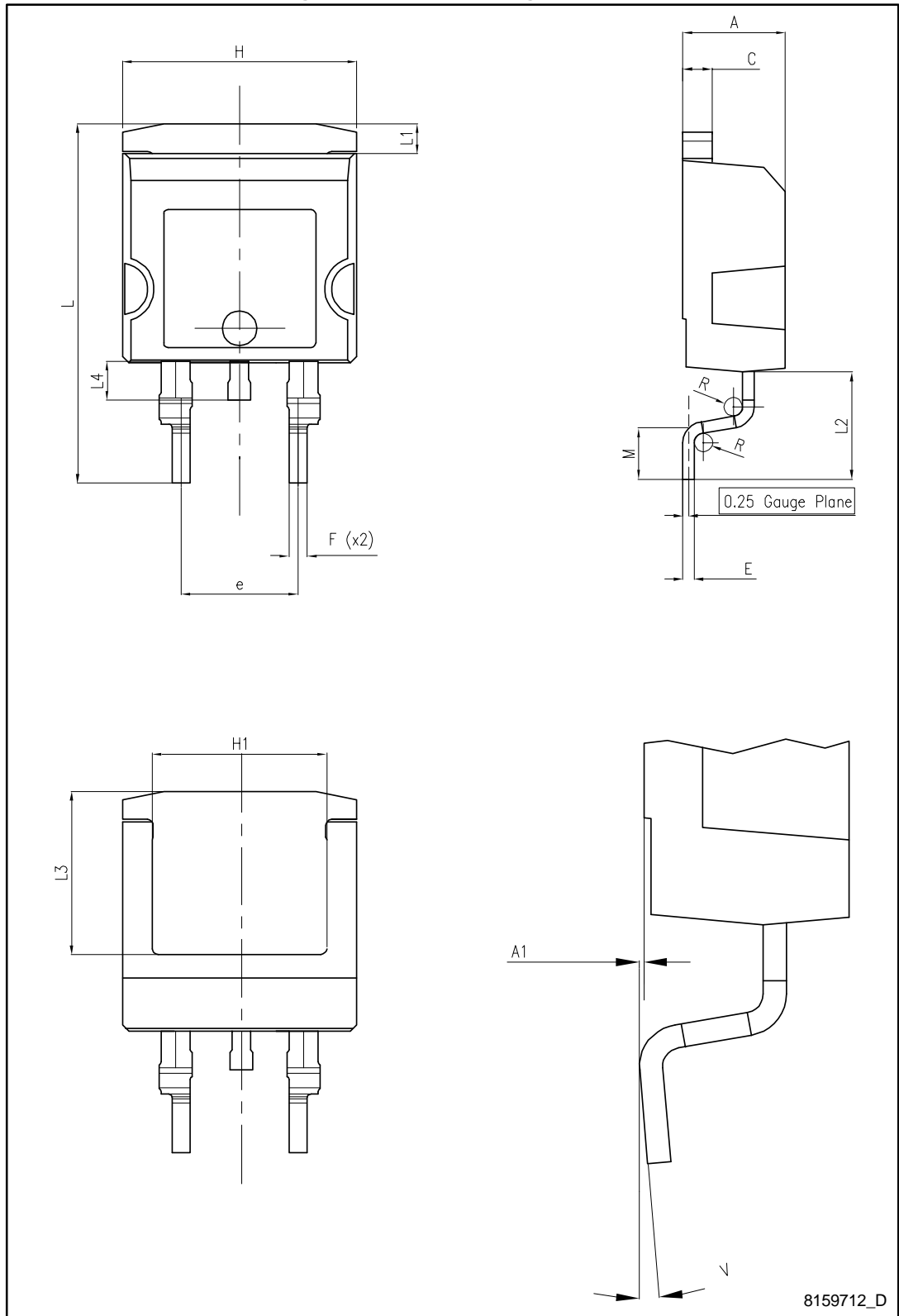
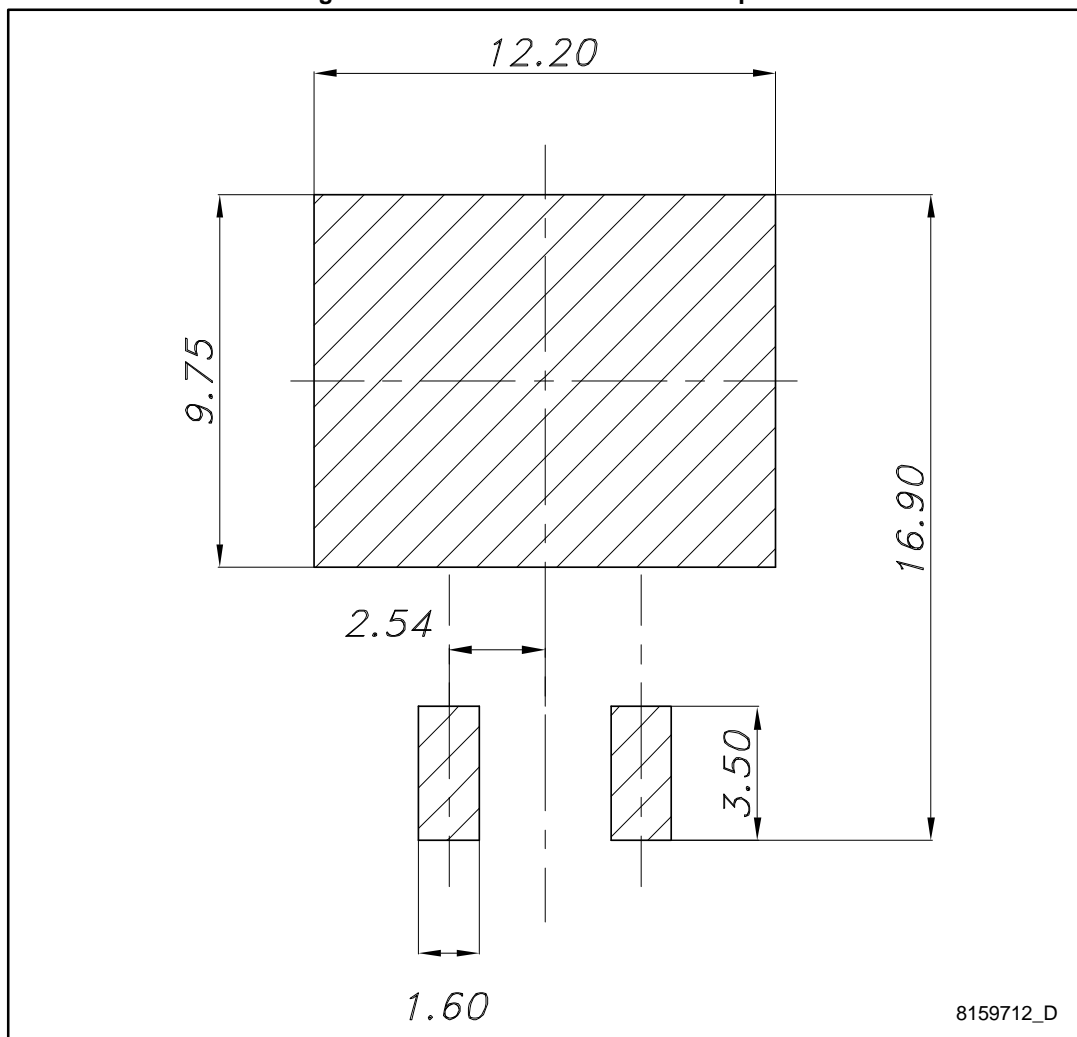


Table 8: H²PAK-2 package mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.30	-	4.80
A1	0.03		0.20
C	1.17		1.37
e	4.98		5.18
E	0.50		0.90
F	0.78		0.85
H	10.00		10.40
H1	7.40		7.80
L	15.30		15.80
L1	1.27		1.40
L2	4.93		5.23
L3	6.85		7.25
L4	1.5		1.7
M	2.6		2.9
R	0.20		0.60
V	0°		8°

Figure 20: H²PAK-2 recommended footprint



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4.2 H2PAK-6 package information

Figure 21: H²PAK-6 package outline

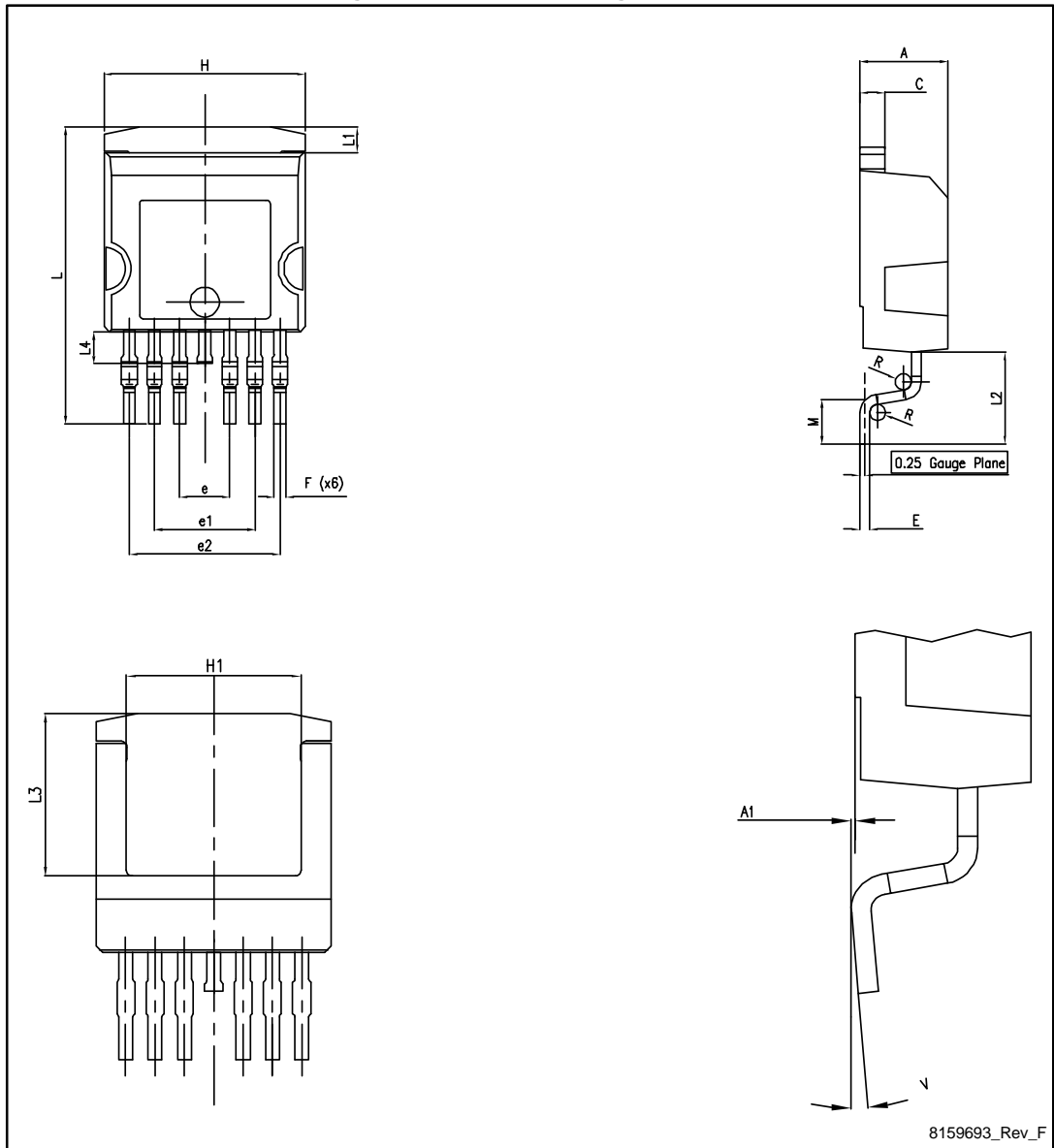
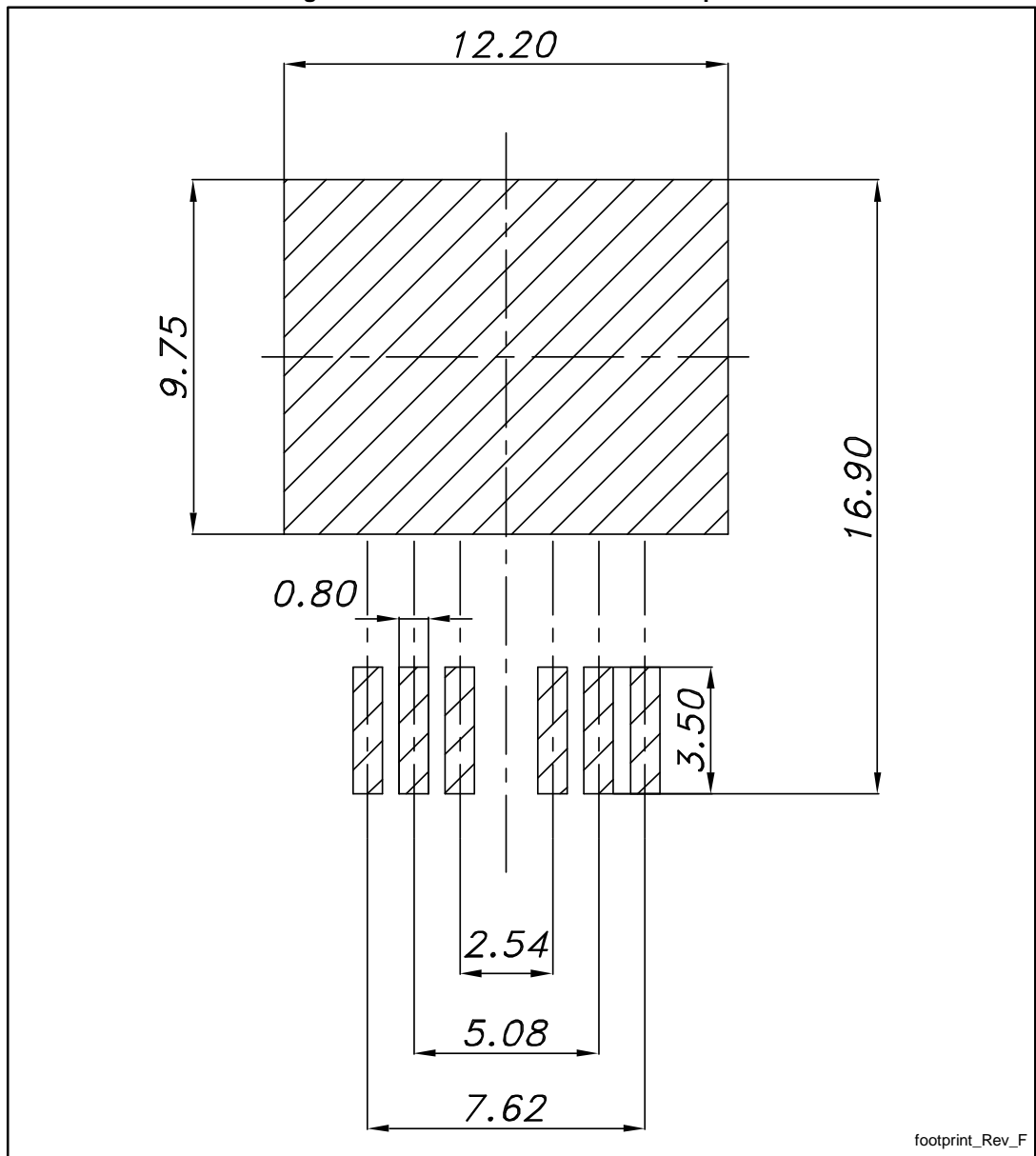


Table 9: H²PAK-6 package mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.30		4.80
A1	0.03		0.20
C	1.17		1.37
e	2.34		2.74
e1	4.88		5.28
e2	7.42		7.82
E	0.45		0.60
F	0.50		0.70
H	10.00		10.40
H1	7.40		7.80
L	14.75		15.25
L1	1.27		1.40
L2	4.35		4.95
L3	6.85		7.25
L4	1.5		1.75
M	1.90		2.50
R	0.20		0.60
V	0°		8°

Figure 22: H²PAK-6 recommended footprint



Dimensions are in mm.

4.3 Packing information

Figure 23: Tape outline

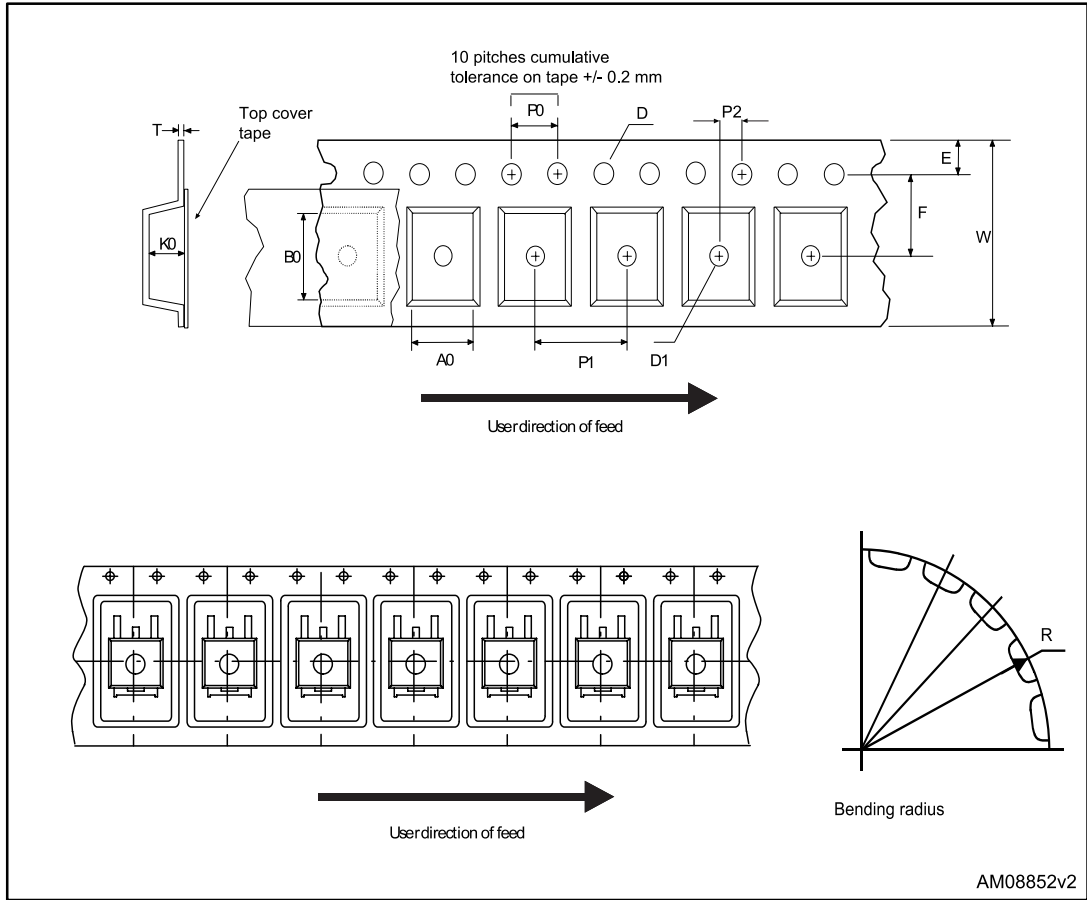


Figure 24: Reel outline

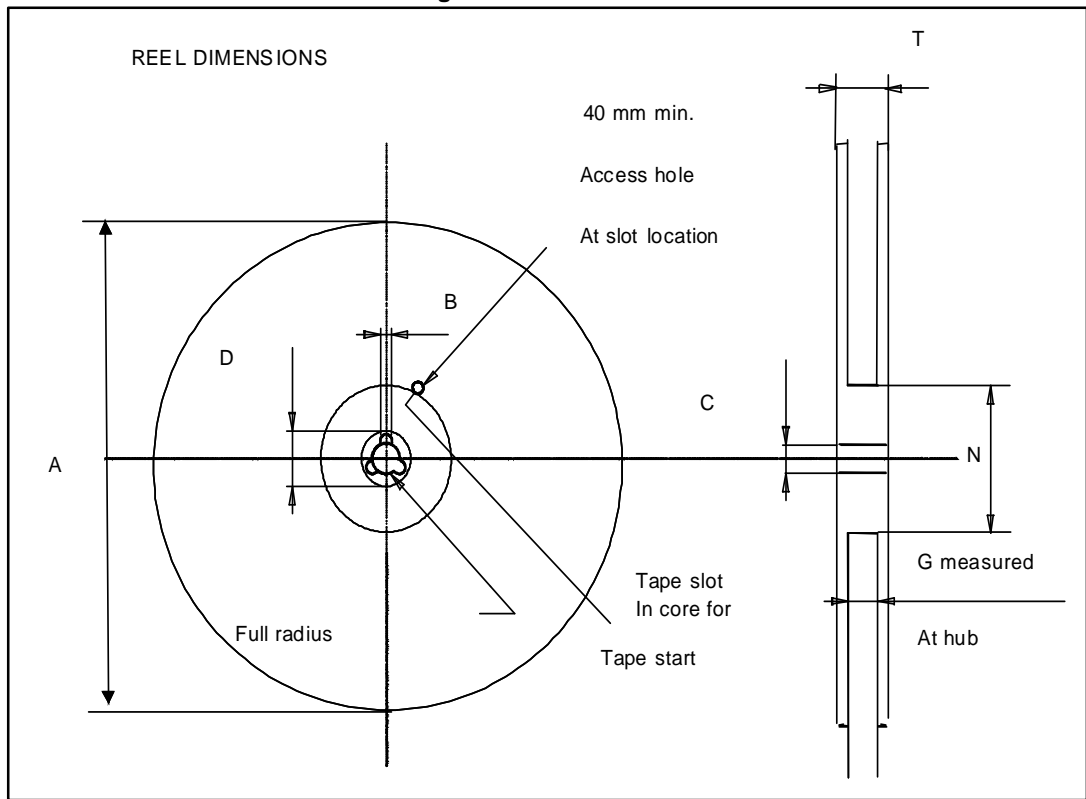


Table 10: Tape and reel mechanical data

Tape			Reel		
Dim.	mm		Dim.	mm	
	Min.	Max.		Min.	Max.
A0	10.5	10.7	A		330
B0	15.7	15.9	B	1.5	
D	1.5	1.6	C	12.8	13.2
D1	1.59	1.61	D	20.2	
E	1.65	1.85	G	24.4	26.4
F	11.4	11.6	N	100	
K0	4.8	5.0	T		30.4
P0	3.9	4.1			
P1	11.9	12.1	Base quantity		1000
P2	1.9	2.1	Bulk quantity		1000
R	50				
T	0.25	0.35			
W	23.7	24.3			

5 Revision history

Table 11: Document revision history

Date	Revision	Changes
10-Dec-2012	1	Initial release. Part number(s) previously included in datasheet ID02287
23-Jul-2013	2	<ul style="list-style-type: none">• Document status promoted from preliminary to production data• Modified: I_{DSS} and V_{GS} value in table 4• Added: E_{AS} value in table 2• Minor text changes
27-Nov-2014	3	<ul style="list-style-type: none">• Updated: H²PAK-6 package information.• Updated the title, features and description.• Minor text changes.
29-Jul-2015	4	Updated Table 2: "Absolute maximum ratings" .

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